



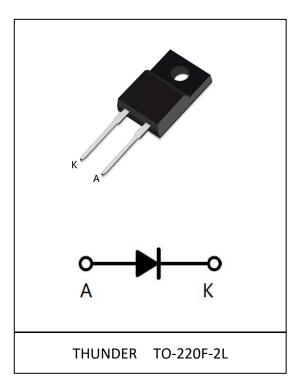
**Thunder High Power Products** 

# FRED Ultrafast Soft Recovery Diode, 30A

#### Features:

- Ultrafast Recovery
- 175°C operating junction temperature
- High frequency operation
- Low power loss, less RFI and EMI
- Low I<sub>R</sub> value
- High surge capacity
- Epitaxial chip construction

Product Summary		
VR	600V	
IF(AV)	30A	
trr	24ns	



### **Description/Applications**

These diodes are optimized to less losses and EMI/RFI in high frequency power conditioning system. The soft recovery behavior of the diodes offers the need as snubber in most applications. These devices are ideally suited for applications where the switching losses are not significant portion of the total losses.

### **Absolute Maximum Ratings**

Parameter	Symbol	Test Conditions	Values	Units
Repetitive peak reverse voltage	Vrrm		600	V
Continuous forward current	lf(AV)	Tc =110°C	30	
Single pulse forward current	IFSM	Tc =25°C	300	A
Maximum repetitive forward current	IFRM	Square wave, 20kHZ	55	
Operating junction	Tj		175	°C
Storage temperatures	Tstg		-55 to +175	°C





# Electrical characteristics (Ta=25°Cunless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Тур.	Max.	Units
Breakdown voltage	Vbr,	Ir=100µA	600			
Blocking voltage	VR					
Forward voltage V		IF=30A		1.70	2.10	V
	VF	IF=30A, Tj =125°C		1.45	1.90	
Reverse leakage current	_	Vr= Vrrm			20	_
	Tj=150°C, Vr=600V			200	μA	
Reverse recovery time	trr	I <sub>F</sub> =1A,V <sub>R</sub> =30V, di/ <i>dt</i> =200A/us		24	35	ns
Reverse recovery time	trr			30		ns
Maximum Reverse Recovery Current	Irm	I <sub>F</sub> =30A,V <sub>R</sub> =300V, d <sub>IF</sub> /dt = -200A/μs ,T <sub>J</sub> =25°C		4.1		А
Reverse Recovery Charge	Qrr			156		nC
Reverse recovery time	trr			95		ns
Maximum Reverse Recovery Current	Irm	I <sub>F</sub> =30A,VR =300V, d <sub>IF</sub> /dt = -200A/μs ,T <sub>J</sub> =125 ℃		8		А
Reverse Recovery Charge	Qrr			950		nC

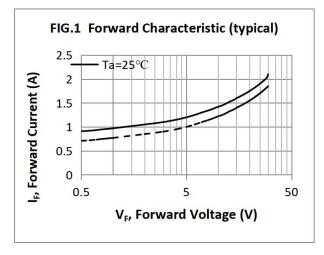
# **Thermal characteristics**

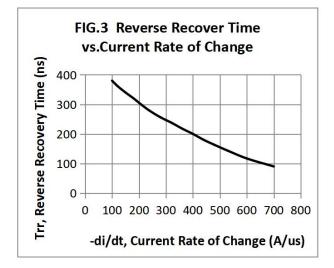
Paramter	Symbol	Тур	Units
Junction-to-Case	R <sub>θ</sub> ιc	2.0	°C/W

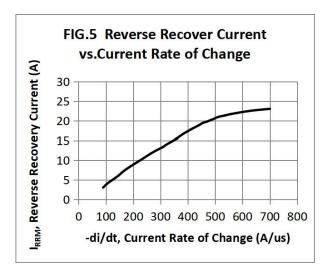


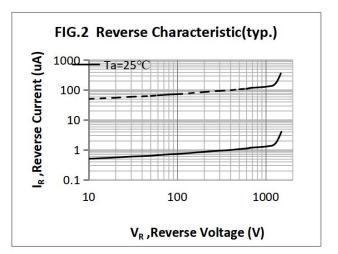
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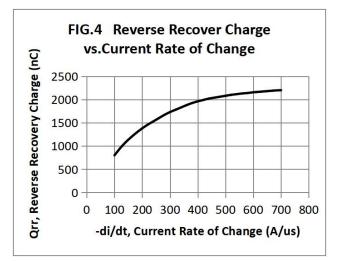
## **Electrical performance (typical)**

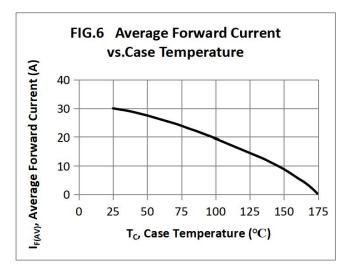










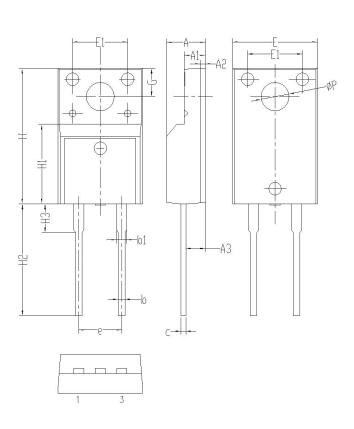






### **Package Information**

#### **TO-220F-2L PACKAGE**



Symbol -		单位 mm	
	Min	Nom	Max
A	4.55	4.75	4. 95
A1	2. 40	2.60	2.80
A2	0.40	0.60	0.80
A3	2.10	2.30	2.50
b1	1.10	1.30	1.50
b	0.60	0.80	1.00
с	0. 42	0.50	0. 58
е	4.88	5.08	<mark>5.</mark> 28
E	9.9	10. 1	10.3
E1	6.8	7	7.2
H	15.8	16.0	16.2
H1	9.10	9.30	9.50
H2	12.5	13.0	<mark>13.</mark> 5
H3	3.10	3. <mark>30</mark>	<mark>3.</mark> 50
G	3.00	3.20	3.40
ΦP	3.00	3.20	3.40

## 基本尺寸

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